



For immediate release

Diodes Incorporated Announces Rugged MOSFETs that Handle the Rigors of VoIP Communication Equipment

Dallas, Texas –June 24, 2010 --- Diodes Incorporated (Nasdaq: DIOD), a leading global manufacturer and supplier of high-quality application specific standard products within the broad discrete, logic and analog semiconductor markets, today has extended its MOSFET product line with the introduction of 60V N-channel devices tailored for use in VoIP communication equipment. Designed to handle the high pulse current needed to generate tip and ring linefeeds and to withstand the avalanche energy induced during switching, the DMN60xx series meets the stringent requirements of the primary switch position in transformer based Subscriber Line Interface Circuits (SLIC) DC/DC converters.

Diodes has introduced four products, offering a choice of four different industry standard package options: DMN6068SE in SOT223, DMN6068LK3 in TO252 and in SO8, the single MOSFET DMN6066SSS and the dual MOSFET DMN6066SSD; the latter replacing two separate devices to help reduce component count and PCB footprint.

The MOSFETs' low gate charge and input capacitance mean that they can be driven with minimal or no buffering at low logic level voltages, so simplifying SLIC circuit design and further reducing component count and cost. Device gate charge and on-resistance performance have been balanced to deliver the requisite figure of merit for VoIP applications, including cable and DSL modems, analog terminal adaptors and private branch exchanges. Further information can be found on the Company's website at <http://www.diodes.com>.

About Diodes Incorporated

Diodes Incorporated (Nasdaq: DIOD), a Standard and Poor's SmallCap 600 and Russell 3000 Index company, is a leading global manufacturer and supplier of high-quality application specific standard products within the broad discrete, logic, and analog semiconductor markets. Diodes serves the consumer electronics, computing, communications, industrial, and automotive markets. Diodes' products include diodes, rectifiers, transistors, MOSFETs, protection devices, functional specific arrays, single gate logic, amplifiers and comparators, Hall-effect and temperature sensors; power management devices, including LED drivers, DC-DC switching and linear voltage regulators, and voltage references along with special function devices, such as USB power switches, load switches, voltage supervisors, and motor controllers. The Company's corporate headquarters, logistics center, and Americas' sales office are located in Dallas, Texas. Design, marketing, and engineering centers are located in Dallas; San Jose, California; Taipei, Taiwan; Manchester, England; and Neuhaus, Germany. The Company's wafer fabrication facilities are located in Kansas City, Missouri and Manchester, with two manufacturing facilities located in Shanghai, China, another in Neuhaus, and a joint venture facility located in Chengdu, China. Additional engineering, sales, warehouse, and logistics offices are located in Taipei; Hong Kong; Manchester; and Munich, Germany; with support offices located throughout the world. For further information, including SEC filings, visit the Company's website at <http://www.diodes.com>.

###

Company Contact:

Diodes Incorporated
Francis Tang
VP, Worldwide Discrete Products
P: 972-385-2810
E: pressinquiries@diodes.com

Investor Relations Contact:

Shelton Group
Leanne K. Sievers
EVP, Investor Relations
P: 949-224-3874
E: lsievers@sheltongroup.com